



# CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

## High Speed CMOS Logic Octal Transparent Latch, Three-State Output

November 1997

### Features

- Common Latch Enable Control
- Common Three-State Output Enable Control
- Buffered Inputs
- Three-State Outputs
- Bus Line Driving Capacity
- Typical Propagation Delay = 12ns at  $V_{CC} = 5V$ ,  $C_L = 15pF$ ,  $T_A = 25^\circ C$  (Data to Output for HC373)
- Fanout (Over Temperature Range)
  - Standard Outputs ..... 10 LSTTL Loads
  - Bus Driver Outputs ..... 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL} = 30\%$ ,  $N_{IH} = 30\%$  of  $V_{CC}$  at  $V_{CC} = 5V$
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,  $V_{IL} = 0.8V$  (Max),  $V_{IH} = 2V$  (Min)
  - CMOS Input Compatibility,  $I_I \leq 1\mu A$  at  $V_{OL}, V_{OH}$

### Description

The Harris CD74HC373, CD74HCT373, CD54HC573, CD74HC573, and CD74HCT573 are high speed Octal Transparent Latches manufactured with silicon gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits, as well as the ability to drive 15 LSTTL devices. The CD74HCT373 and CD74HCT573 are functionally as well as pin compatible with the standard 74LS373 and 74LS573.

The outputs are transparent to the inputs when the latch enable ( $\overline{LE}$ ) is high. When the latch enable ( $\overline{LE}$ ) goes low the data is latched. The output enable ( $\overline{OE}$ ) controls the three-state outputs. When the output enable ( $\overline{OE}$ ) is high the outputs are in the high impedance state. The latch operation is independent to the state of the output enable. The 373 and 573 are identical in function and differ only in their pinout arrangements.

### Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CD54HC573F	-55 to 125	20 Ld CERDIP	F20.3
CD74HC373E	-55 to 125	20 Ld PDIP	F20.3
CD74HCT373E	-55 to 125	20 Ld PDIP	E20.3
CD74HC573E	-55 to 125	20 Ld PDIP	E20.3
CD74HCT573E	-55 to 125	20 Ld PDIP	E20.3
CD74HC373M	-55 to 125	20 Ld SOIC	M20.3
CD74HCT373M	-55 to 125	20 Ld SOIC	M20.3
CD74HC573M	-55 to 125	20 Ld SOIC	M20.3
CD74HCT573M	-55 to 125	20 Ld SOIC	M20.3

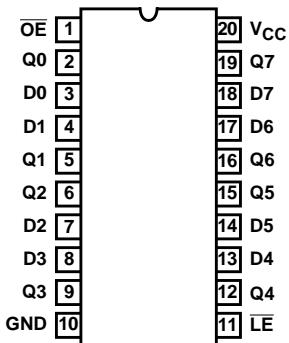
#### NOTES:

1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.
2. Wafer or die for this part number are available which meets all electrical specifications. Please contact your local sales office or Harris customer service for ordering information.

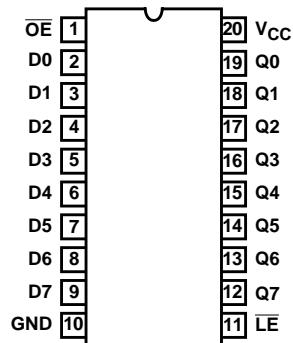
## CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

### Pinout

**CD74HC373, CD74HCT373  
(PDIP, SOIC)  
TOP VIEW**

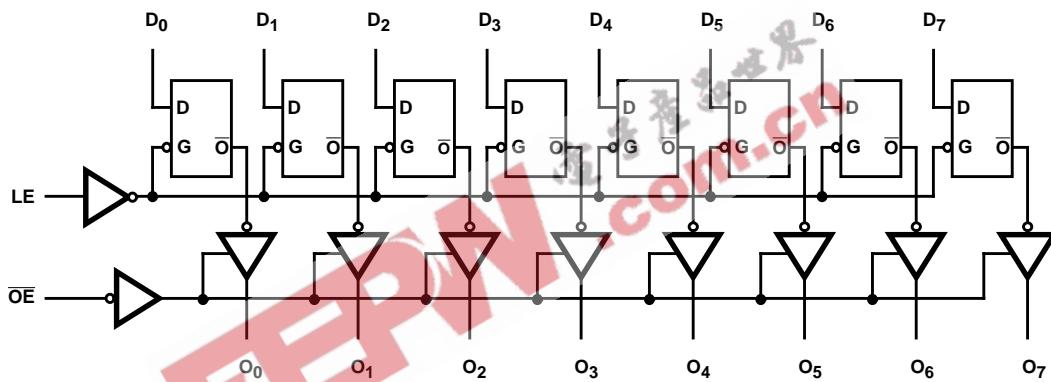


**CD54HC573, CD74HC573, CD74HCT573  
(PDIP, SOIC, CERDIP)  
TOP VIEW**

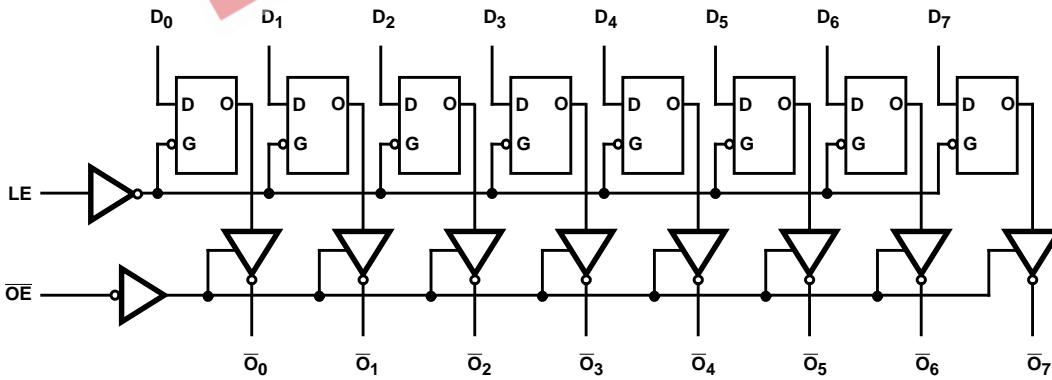


### Functional Block Diagrams

**CD74HC373, CD74HCT373, CD74HC573, CD74HCT573**



**CD74HCT573**



**TRUTH TABLE**

OUTPUT ENABLE	LATCH ENABLE	DATA	OUTPUT
L	H	H	H
L	H	L	L
L	L	I	L
L	L	h	H
H	X	X	Z

NOTE: H = High Voltage Level, L = Low Voltage Level, X = Don't Care, Z = High Impedance State, I = Low voltage level one set-up time prior to the high to low latch enable transition, h = High voltage level one set-up time prior to the high to low latch enable transition.

# CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

## Absolute Maximum Ratings

DC Supply Voltage, V <sub>CC</sub>	.....	-0.5V to 7V
DC Input Diode Current, I <sub>IK</sub>		
For V <sub>I</sub> < -0.5V or V <sub>I</sub> > V <sub>CC</sub> + 0.5V	.....	±20mA
DC Output Diode Current, I <sub>OK</sub>		
For V <sub>O</sub> < -0.5V or V <sub>O</sub> > V <sub>CC</sub> + 0.5V	.....	±20mA
DC Drain Current, per Output, I <sub>O</sub>		
For -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V	.....	±35mA
DC Output Source or Sink Current per Output Pin, I <sub>O</sub>		
For V <sub>O</sub> > -0.5V or V <sub>O</sub> < V <sub>CC</sub> + 0.5V	.....	±25mA
DC V <sub>CC</sub> or Ground Current, I <sub>CC</sub>	.....	±50mA

## Thermal Information

Thermal Resistance (Typical, Note 3)	θ <sub>JA</sub> (°C/W)	θ <sub>JA</sub> (°C/W)
PDIP Package	125	N/A
CERDIP Package	85	24
SOIC Package	120	N/A
Maximum Junction Temperature (Plastic Package)	.....	150°C
Maximum Storage Temperature Range	.....	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	.....	300°C
(SOIC - Lead Tips Only)		

## Operating Conditions

Temperature Range, T <sub>A</sub>	.....	-55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>		
HC Types	.....	2V to 6V
HCT Types	.....	4.5V to 5.5V
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub>	.....	0V to V <sub>CC</sub>
Input Rise and Fall Time		
2V	.....	1000ns (Max)
4.5V	.....	500ns (Max)
6V	.....	400ns (Max)

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### NOTE:

3. θ<sub>JA</sub> is measured with the component mounted on an evaluation PC board in free air.

## DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS		V <sub>CC</sub> (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS			
		V <sub>I</sub> (V)	I <sub>O</sub> (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX				
<b>HC TYPES</b>															
High Level Input Voltage	V <sub>IH</sub>	-	-	2 4.5 6	2	1.5	-	-	1.5	-	1.5	-	V		
					3.15	-	-	3.15	-	3.15	-	3.15	V		
					4.2	-	-	4.2	-	4.2	-	4.2	V		
Low Level Input Voltage	V <sub>IL</sub>	-	-	2 4.5 6	2	-	-	0.5	-	0.5	-	0.5	V		
					-	-	1.35	-	1.35	-	1.35	1.35	V		
					-	-	1.8	-	1.8	-	1.8	1.8	V		
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	1.9	V		
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	4.4	V		
			-0.02	6	5.9	-	-	5.9	-	5.9	-	5.9	V		
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	3.7	V		
			-7.8	6	5.48	-	-	5.34	-	5.2	-	5.2	V		
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	0.1	V		
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	0.1	V		
			0.02	6	-	-	0.1	-	0.1	-	0.1	0.1	V		
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	0.4	V		
			7.8	6	-	-	0.26	-	0.33	-	0.4	0.4	V		
Input Leakage Current	I <sub>I</sub>	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	±1	µA		
Quiescent Device Current	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	160	µA		

## CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

### DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V <sub>CC</sub> (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V <sub>I</sub> (V)	I <sub>O</sub> (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Three-State Leakage Current	-	V <sub>IL</sub> or V <sub>IH</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	6	-	-	±0.5	-	±5	-	±10	µA
<b>HCT TYPES</b>												
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
			7.8	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I <sub>I</sub>	V <sub>CC</sub> to GND	-	5.5	-	-	±0.1	-	±1	-	±1	µA
Quiescent Device Current	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	µA
Three-State Leakage Current	-	V <sub>IL</sub> or V <sub>IH</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	6	-	-	±0.5	-	±5	-	±10	µA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load (Note 4)	ΔI <sub>CC</sub>	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	µA

NOTE:

4. For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

### HCT Input Loading Table

INPUT	UNIT LOADS	
	HCT373	HCT573
OE	1.5	1.25
Dn	0.4	0.3
LE	0.6	0.65

NOTE: Unit Load is ΔI<sub>CC</sub> limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

## CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

### Prerequisite For Switching Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	V <sub>CC</sub> (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
<b>HC TYPES</b>											
LE Pulse Width	t <sub>W</sub>	-	2	80	-	-	100	-	120	-	ns
			4.5	16	-	-	20	-	24	-	ns
			6	14	-	-	17	-	20	-	ns
Set-up Time Data to LE	t <sub>SU</sub>	-	2	50	-	-	65	-	75	-	ns
			4.5	10	-	-	13	-	15	-	ns
			6	9	-	-	11	-	13	-	ns
Hold Time, Data to LE (573)	t <sub>H</sub>	-	2	40	-	-	50	-	60	-	ns
			4.5	8	-	-	10	-	12	-	ns
			6	7	-	-	9	-	10	-	ns
Hold Time, Data to LE (373)	t <sub>H</sub>	-	2	5	-	-	5	-	5	-	ns
			4.5	5	-	-	5	-	5	-	ns
			6	5	-	-	5	-	5	-	ns
<b>HCT TYPES</b>											
LE Pulse Width	t <sub>W</sub>	-	4.5	16	-	-	20	-	24	-	ns
Set-up Time Data to LE	t <sub>W</sub>	-	4.5	13	-	-	16	-	20	-	ns
Hold Time, Data to LE	t <sub>H</sub>	-	4.5	10	-	-	13	-	15	-	ns

**Switching Specifications** Input t<sub>p</sub>, t<sub>f</sub> = 6ns

PARAMETER	SYMBOL	TEST CONDITIONS	V <sub>CC</sub> (V)	25°C		-40°C TO 85°C		-55°C TO 125°C		UNITS
				TYP	MAX	MAX	MAX	MAX	MAX	
<b>HC TYPES</b>										
Propagation Delay, Data to Qn (HC/HCT373)	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	150	190	225	-	-	ns
			4.5	-	30	38	45	-	-	ns
			6	-	26	33	38	-	-	ns
		C <sub>L</sub> = 15pF	5	12	-	-	-	-	-	ns
Propagation Delay, Data to Qn (HC/HCT573)	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	175	220	265	-	-	ns
			4.5	-	35	44	53	-	-	ns
			6	-	30	37	45	-	-	ns
		C <sub>L</sub> = 15pF	5	14	-	-	-	-	-	ns
Propagation Delay, LE to Qn	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	175	220	265	-	-	ns
			4.5	-	35	44	53	-	-	ns
			6	-	30	37	45	-	-	ns
		C <sub>L</sub> = 15pF	5	14	-	-	-	-	-	ns
Output Enabling Time	t <sub>PZL</sub> , t <sub>PZH</sub>	C <sub>L</sub> = 50pF	2	-	150	190	225	-	-	ns
			4.5	-	30	38	45	-	-	ns
			6	-	26	33	38	-	-	ns
		C <sub>L</sub> = 15pF	5	12	-	-	-	-	-	ns

## CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

### Switching Specifications Input $t_p, t_f = 6\text{ns}$ (Continued)

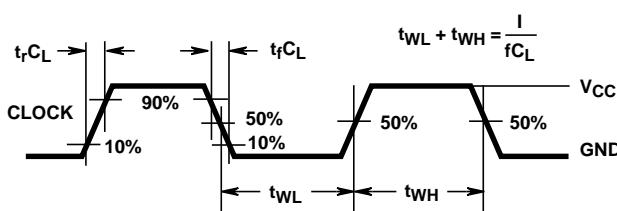
PARAMETER	SYMBOL	TEST CONDITIONS	$V_{CC}$ (V)	25°C		-40°C TO 85°C	-55°C TO 125°C	UNITS
				TYP	MAX	MAX	MAX	
Output Disabling Time	$t_{PLZ}, t_{PHZ}$	$C_L = 50\text{pF}$	2	-	150	190	225	ns
			4.5	-	30	38	45	ns
			6	-	26	33	38	ns
		$C_L = 15\text{pF}$	5	12	-	-	-	ns
Output Transition Time	$t_{TLH}, t_{THL}$	$C_L = 50\text{pF}$	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	$C_I$	-	-	-	10	10	10	pF
Three-State Output Capacitance	$C_O$	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 5, 6)	$C_{PD}$	-	5	51	-	-	-	pF
<b>HCT TYPES</b>								
Propagation Delay, Data to Qn (HC/HCT373)	$t_{PLH}, t_{PHL}$	$C_L = 50\text{pF}$	4.5	-	32	40	48	ns
		$C_L = 15\text{pF}$	5	13	-	-	-	ns
Propagation Delay, Data to Qn (HC/HCT573)	$t_{PLH}, t_{PHL}$	$C_L = 50\text{pF}$	4.5	-	35	44	53	ns
		$C_L = 15\text{pF}$	5	17	-	-	-	ns
Propagation Delay, $\overline{LE}$ to Qn	$t_{PLH}, t_{PHL}$	$C_L = 50\text{pF}$	4.5	-	35	44	53	ns
		$C_L = 15\text{pF}$	5	14	-	-	-	ns
Output Enabling Time	$t_{PZL}, t_{PZH}$	$C_L = 50\text{pF}$	4.5	-	35	44	53	ns
		$C_L = 15\text{pF}$	5	14	-	-	-	ns
Output Disabling Time	$t_{PLZ}, t_{PZH}$	$C_L = 50\text{pF}$	4.5	-	35	44	53	ns
		$C_L = 15\text{pF}$	5	14	-	-	-	ns
Output Transition Time	$t_{TLH}, t_{THL}$	$C_L = 50\text{pF}$	4.5	-	12	15	18	ns
Input Capacitance	$C_I$	-	-	-	10	10	10	pF
Three-State Output Capacitance	$C_O$	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 5, 6)	$C_{PD}$	-	5	53	-	-	-	pF

#### NOTES:

5.  $C_{PD}$  is used to determine the no-load dynamic power consumption, per latch.
6.  $P_D$  (total power per latch) =  $V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = Input Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

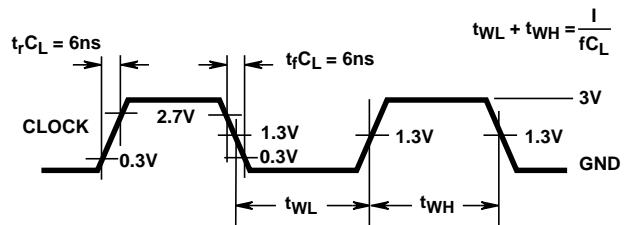
## CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

### Test Circuits and Waveforms



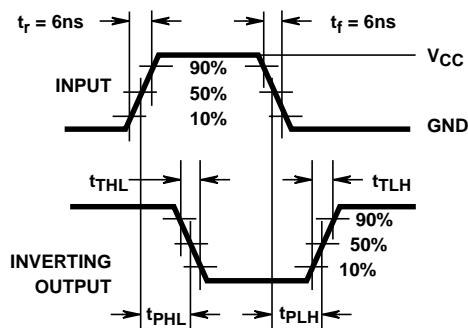
NOTE: Outputs should be switching from 10%  $V_{CC}$  to 90%  $V_{CC}$  in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

**FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH**

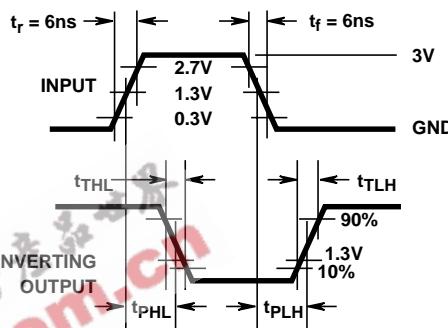


NOTE: Outputs should be switching from 10%  $V_{CC}$  to 90%  $V_{CC}$  in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

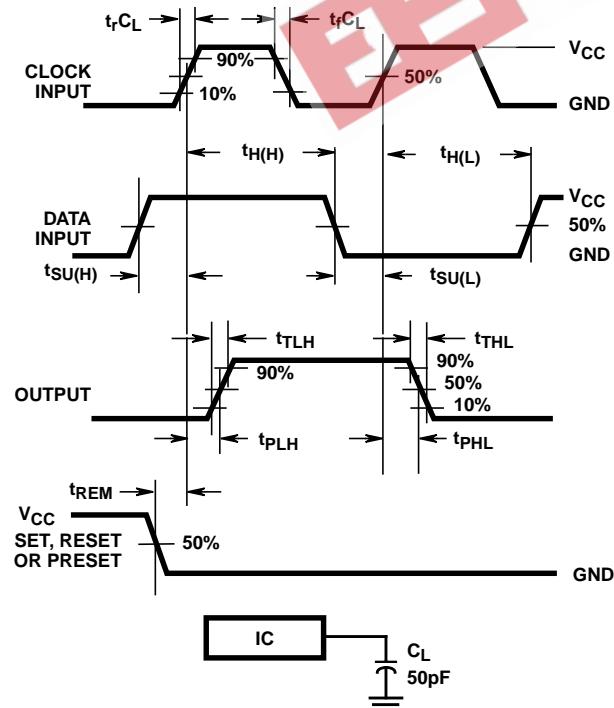
**FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH**



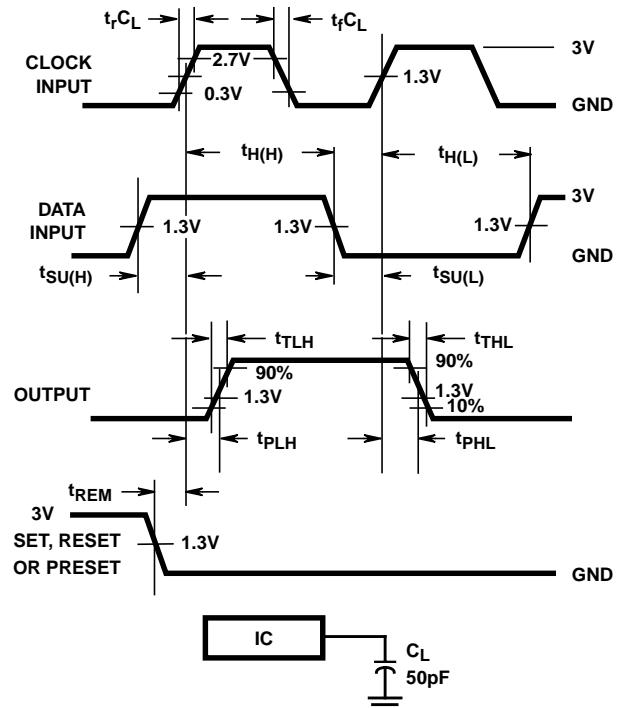
**FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC**



**FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC**



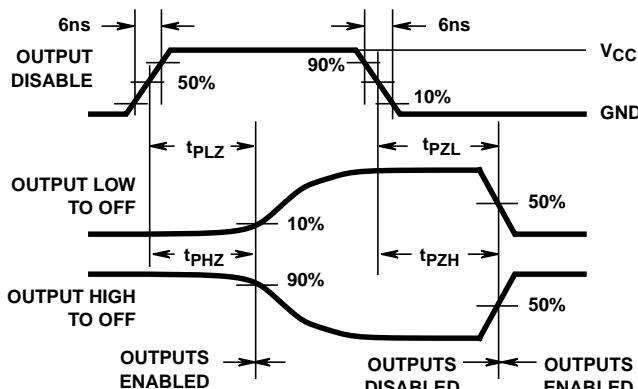
**FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS**



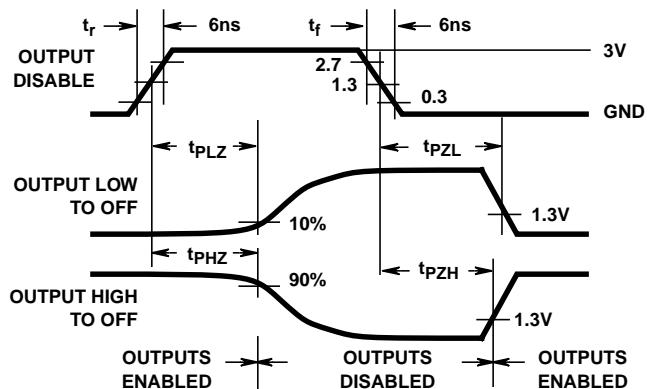
**FIGURE 6. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS**

## CD74HC373, CD74HCT373, CD54HC573, CD74HC573, CD74HCT573

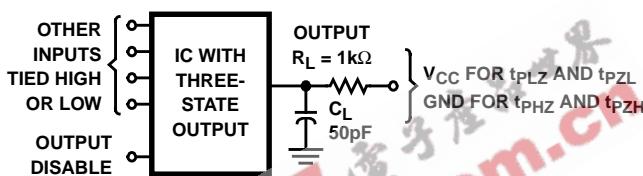
### Test Circuits and Waveforms (Continued)



**FIGURE 7. HC THREE-STATE PROPAGATION DELAY WAVEFORM**



**FIGURE 8. HCT THREE-STATE PROPAGATION DELAY WAVEFORM**



NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1\text{k}\Omega$  to  $V_{CC}$ ,  $C_L = 50\text{pF}$ .

**FIGURE 9. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT**

All Harris Semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

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